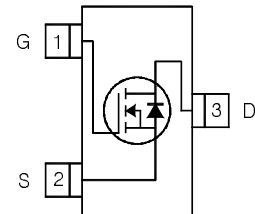
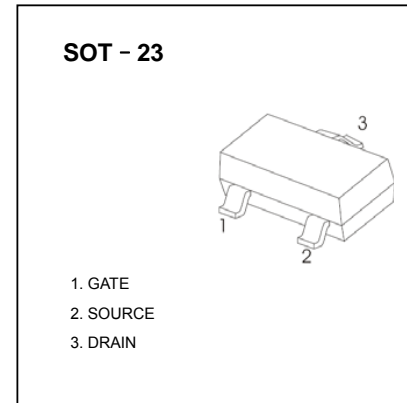


### FEATURES

- $V_{DS} (V) = -30V$
- $R_{DS(ON)} < 46m\Omega$  ( $V_{GS} = -10V$ )
- $R_{DS(ON)} < 54m\Omega$  ( $V_{GS} = -4.5V$ )

### APPLICATIONS

- For Mobile Computing
- Load Switch
- Notebook Adaptor Switch
- DC/DC Converter



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	- 30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current ( $T_J = 150\text{ }^\circ\text{C}$ )	$I_D$	$T_C = 25\text{ }^\circ\text{C}$	- 5.6
		$T_C = 70\text{ }^\circ\text{C}$	- 5.1
		$T_A = 25\text{ }^\circ\text{C}$	- 5.4 <sup>b,c</sup>
		$T_A = 70\text{ }^\circ\text{C}$	- 4.3 <sup>b,c</sup>
Pulsed Drain Current ( $t = 100\text{ }\mu\text{s}$ )	$I_{DM}$	- 18	A
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25\text{ }^\circ\text{C}$	
		$T_A = 25\text{ }^\circ\text{C}$	- 1 <sup>b,c</sup>
Maximum Power Dissipation	$P_D$	$T_C = 25\text{ }^\circ\text{C}$	2.5
		$T_C = 70\text{ }^\circ\text{C}$	1.6
		$T_A = 25\text{ }^\circ\text{C}$	1.25 <sup>b,c</sup>
		$T_A = 70\text{ }^\circ\text{C}$	0.8 <sup>b,c</sup>
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	$^\circ\text{C}$

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>b,d</sup>	$R_{thJA}$	75	100	$^\circ\text{C/W}$
Maximum Junction-to-Foot (Drain)	$R_{thJF}$	40	50	

#### Notes:

- Based on  $T_C = 25\text{ }^\circ\text{C}$ .
- Surface mounted on 1" x 1" FR4 board.
- $t = 5\text{ s}$ .
- Maximum under steady state conditions is 166  $^\circ\text{C/W}$ .

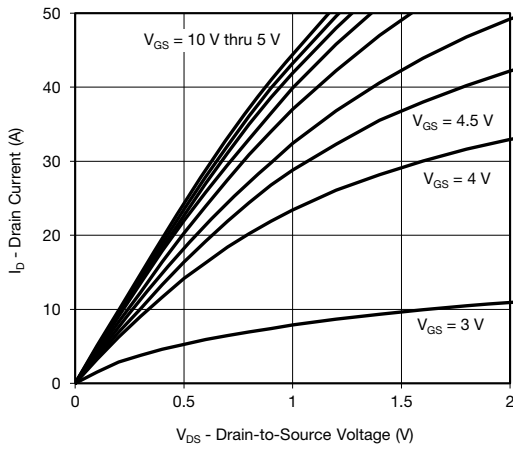
**SPECIFICATIONS** ( $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	-30			V
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = -250\text{ }\mu\text{A}$		-19		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$		4			
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	-0.5		-2.0	V
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$			-1	$\mu\text{A}$
		$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$			-5	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \leq -5\text{ V}, V_{GS} = -10\text{ V}$	-2.5			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = -10\text{ V}, I_D = -4.4\text{ A}$		46	55	m $\Omega$
		$V_{GS} = -4.5\text{ V}, I_D = -3.6\text{ A}$		54	63	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = -15\text{ V}, I_D = -3.4\text{ A}$		18		S
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = -15\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		1295		$\mu\text{F}$
Output Capacitance	$C_{oss}$		150			
Reverse Transfer Capacitance	$C_{rss}$		130			
Total Gate Charge	$Q_g$	$V_{DS} = -15\text{ V}, V_{GS} = -10\text{ V}, I_D = -5.4\text{ A}$		24	36	nC
				11.4	17	
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -15\text{ V}, V_{GS} = -4.5\text{ V}, I_D = -5.4\text{ A}$		3.4		nC
Gate-Drain Charge	$Q_{gd}$		3.8			
Gate Resistance	$R_g$	$f = 1\text{ MHz}$	1.5	7.7	15.4	$\Omega$
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -15\text{ V}, R_L = 3.5\text{ }\Omega$ $I_D \cong -4.3\text{ A}, V_{GEN} = -10\text{ V}, R_g = 1\text{ }\Omega$		13	20	ns
Rise Time	$t_r$		4	8		
Turn-Off Delay Time	$t_{d(off)}$		38	57		
Fall Time	$t_f$		6	12		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -15\text{ V}, R_L = 3.5\text{ }\Omega$ $I_D \cong -4.3\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 1\text{ }\Omega$		28	42	
Rise Time	$t_r$		16	24		
Turn-Off Delay Time	$t_{d(off)}$		30	45		
Fall Time	$t_f$		10	20		
<b>Drain-Source Body Diode Characteristics</b>						
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25\text{ }^\circ\text{C}$			-2.1	A
Pulse Diode Forward Current ( $t = 100\text{ }\mu\text{s}$ )	$I_{SM}$				-80	
Body Diode Voltage	$V_{SD}$	$I_S = -4.3\text{ A}, V_{GS} = 0\text{ V}$		-0.8	-1.2	V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = -4.3\text{ A}, di/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^\circ\text{C}$		15	23	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$		7	14	nC	
Reverse Recovery Fall Time	$t_a$		8		ns	
Reverse Recovery Rise Time	$t_b$		7			

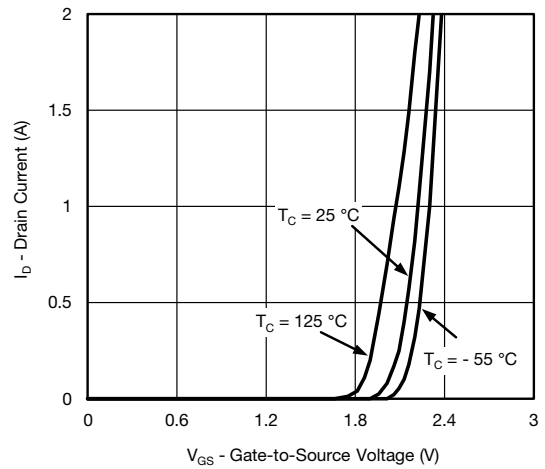
Notes:

- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .  
b. Guaranteed by design, not subject to production testing.

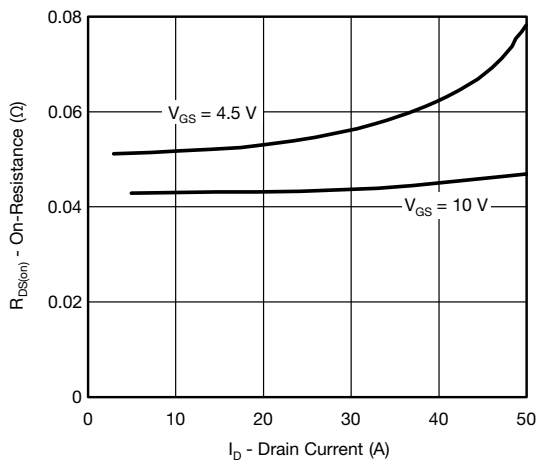
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



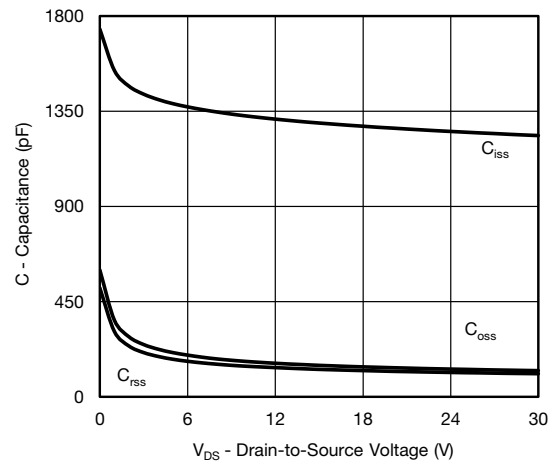
**Output Characteristics**



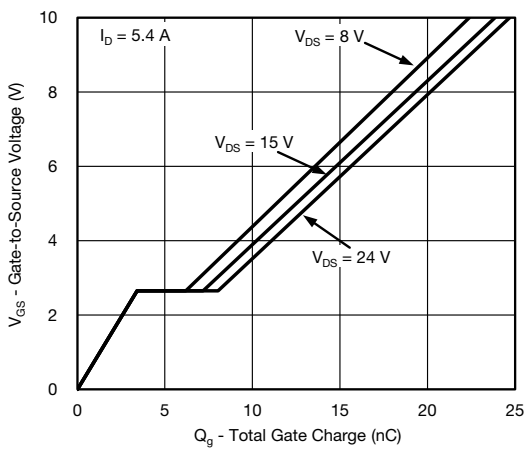
**Transfer Characteristics**



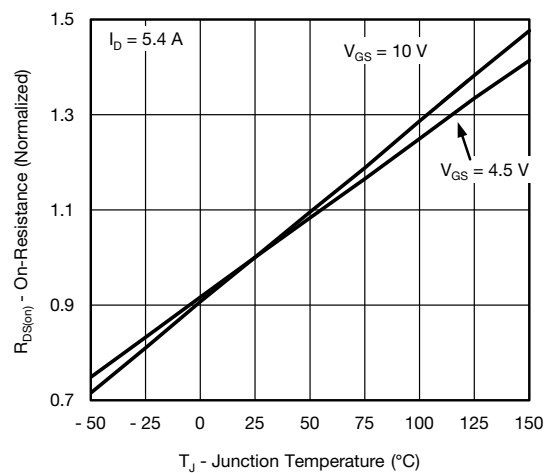
**On-Resistance vs. Drain Current**



**Capacitance**

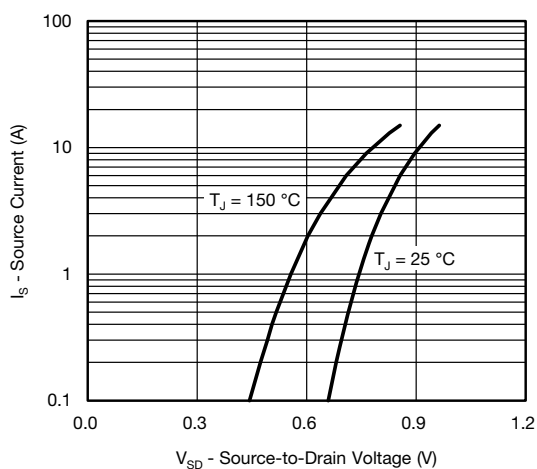


**Gate Charge**

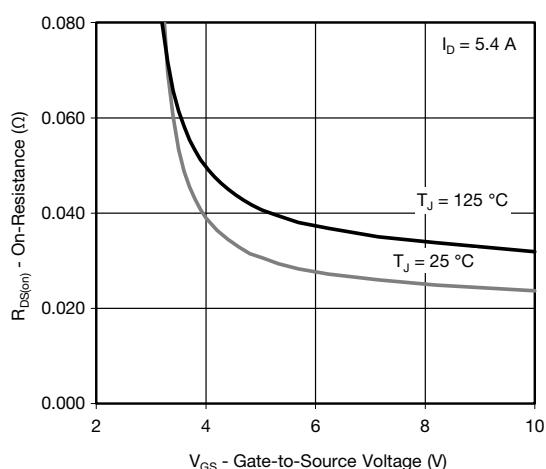


**On-Resistance vs. Junction Temperature**

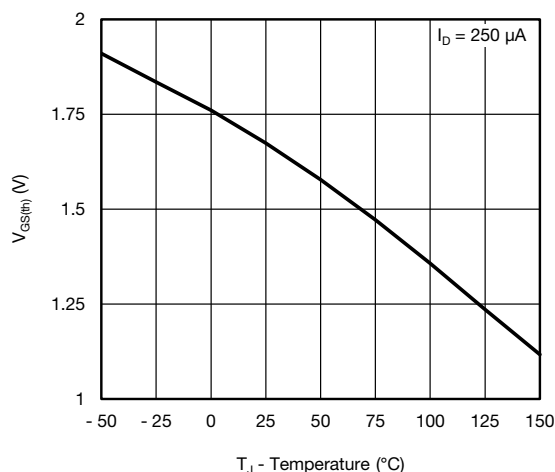
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



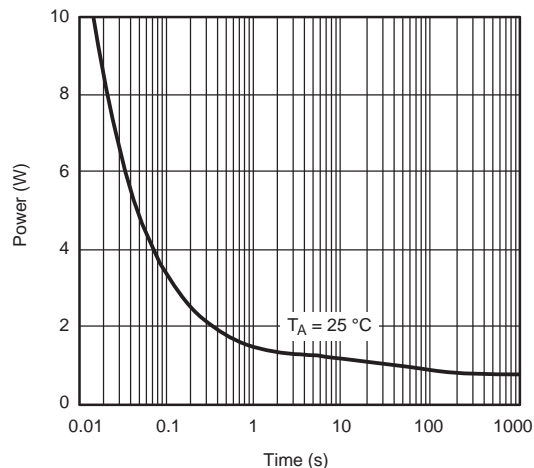
**Source-Drain Diode Forward Voltage**



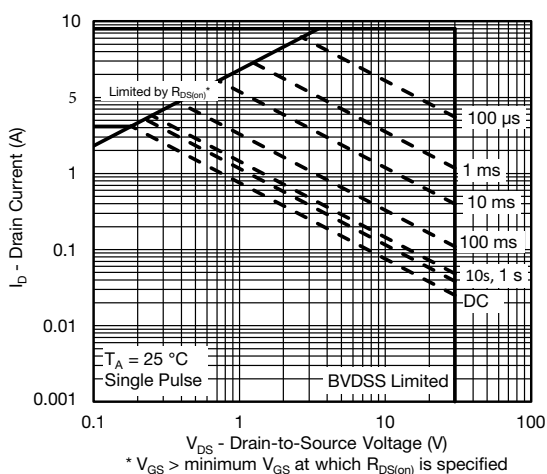
**On-Resistance vs. Gate-to-Source Voltage**



**Threshold Voltage**

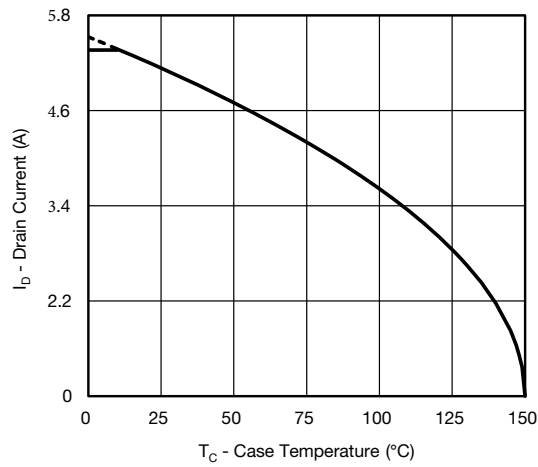


**Single Pulse Power (Junction-to-Ambient)**

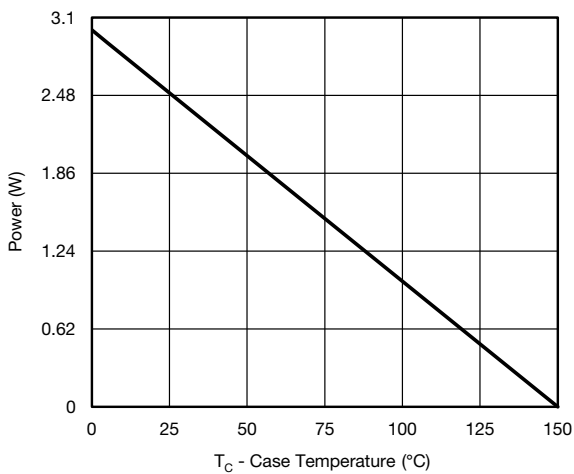


**Safe Operating Area, Junction-to-Ambient**

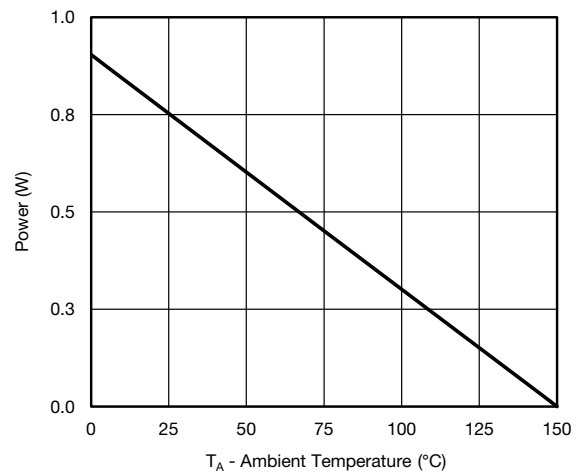
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating\*



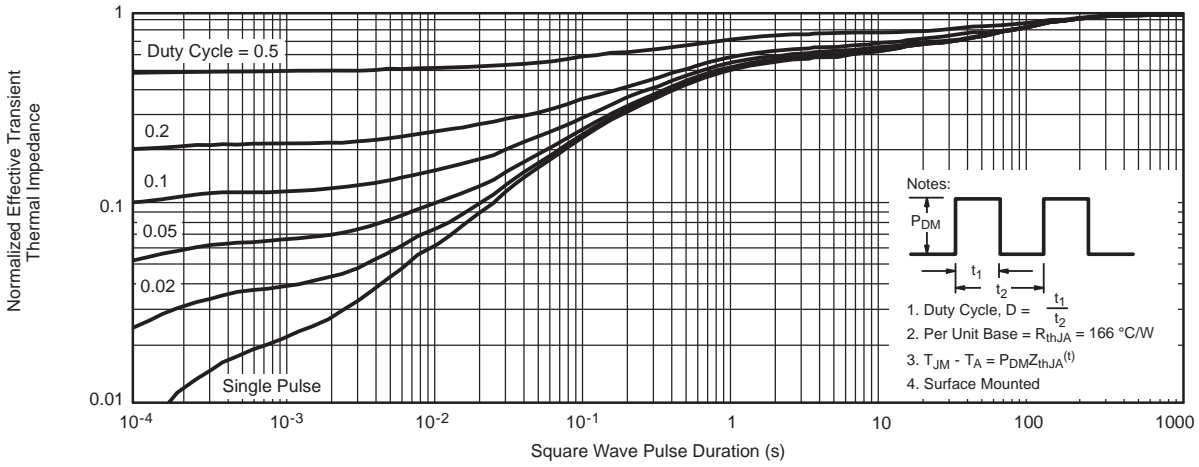
Power, Junction-to-Foot



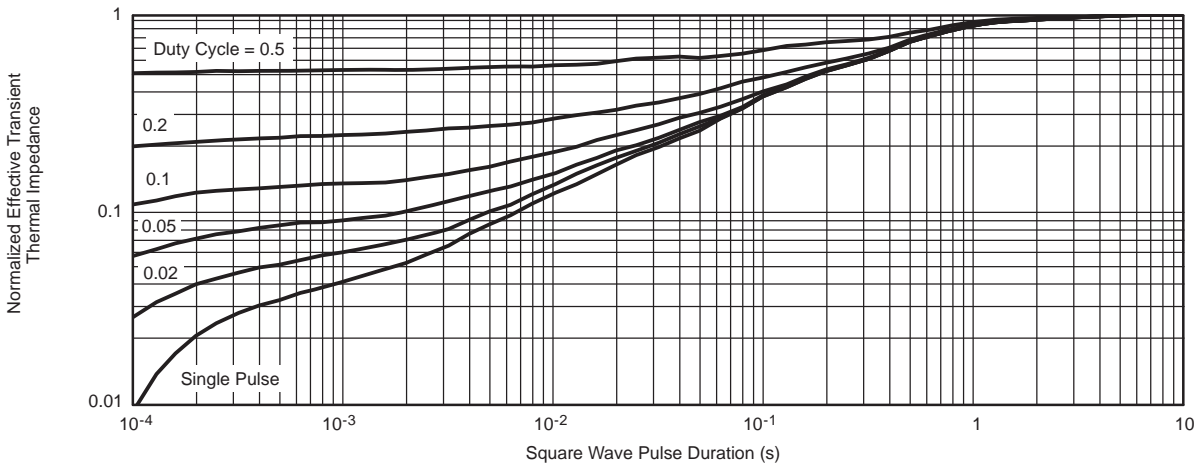
Power, Junction-to-Ambient

\* The power dissipation  $P_D$  is based on  $T_{J(max.)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

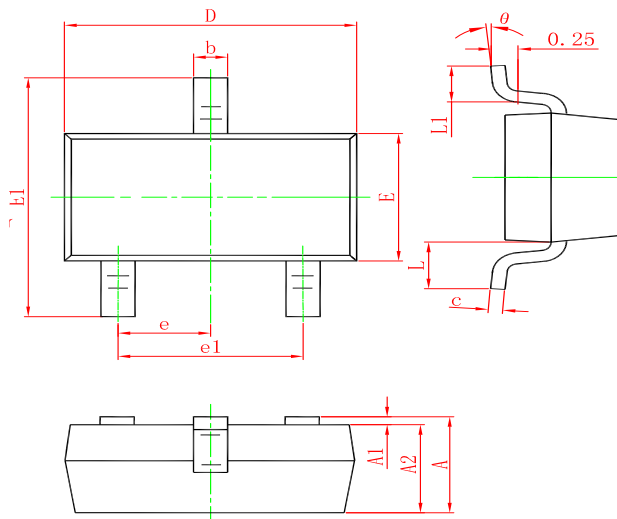


Normalized Thermal Transient Impedance, Junction-to-Ambient



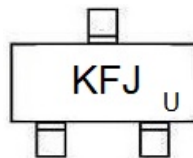
Normalized Thermal Transient Impedance, Junction-to-Foot

### SOT-23 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
theta	0°	8°	0°	8°

### Marking



### Ordering information

Order code	Package	Baseqty	Deliverymode
SSM3J332R	SOT-23	3000	Tape and reel